

INVERTER GRADE THYRISTORS

Puk Version

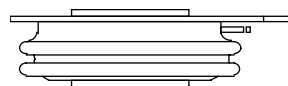
Features

- Metal case with ceramic insulator
- International standard case TO-200AB (E-PUK)
- All diffused design
- Center amplifying gate
- Guaranteed high dV/dt
- Guaranteed high dI/dt
- High surge current capability
- Low thermal impedance
- High speed performance

Typical Applications

- Inverters
- Choppers
- Induction heating
- All types of force-commutated converters

620A



case style TO-200AB (E-PUK)

Major Ratings and Characteristics

Parameters	ST303C..C	Units
$I_{T(AV)}$	620	A
@ T_{hs}	55	°C
$I_{T(RMS)}$	1180	A
@ T_{hs}	25	°C
I_{TSM}	@ 50Hz	7950
	@ 60Hz	8320
I^2t	@ 50Hz	316
	@ 60Hz	289
V_{DRM}/V_{RRM}	400 to 1200	V
t_q range (*)	10 to 30	μs
T_J	- 40 to 125	°C

(*) $t_q = 10$ to $20\mu s$ for 400 to 800V devices
 $t_q = 15$ to $30\mu s$ for 1000 to 1200V devices

ST303C..C Series

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ELECTRICAL SPECIFICATIONS

Voltage Ratings

Type number	Voltage Code	V_{DRM}/V_{RRM} , maximum repetitive peak voltage V	V_{RSM} , maximum non-repetitive peak voltage V	I_{DRM}/I_{RRM} max. @ $T_J = T_J$ max. mA
ST303C..C	04	400	500	50
	08	800	900	
	10	1000	1100	
	12	1200	1300	

Current Carrying Capability

Frequency							Units
50Hz	1314	1130	2070	1940	6930	6270	A
400Hz	1260	1040	2190	1880	3440	2960	
1000Hz	900	700	1900	1590	1850	1540	
2500Hz	340	230	910	710	740	560	
Recovery voltage Vr	50	50	50	50	50	50	V
Voltage before turn-on Vd	V _{DRM}		V _{DRM}		V _{DRM}		
Rise of on-state current di/dt	50	50	-	-	-	-	A/µs
Heatsink temperature	40	55	40	55	40	55	°C
Equivalent values for RC circuit	10Ω / 0.47µF		10Ω / 0.47µF		10Ω / 0.47µF		

On-state Conduction

Parameter	ST303C..C	Units	Conditions
$I_{T(AV)}$ Max. average on-state current @ Heatsink temperature	620 (230)	A	180° conduction, half sine wave double side (single side) cooled
	55 (85)	°C	
$I_{T(RMS)}$ Max. RMS on-state current	1180	A	DC @ 25°C heatsink temperature double side cooled
I_{TSM} Max. peak, one half cycle, non-repetitive surge current	7950		t = 10ms No voltage
	8320		t = 8.3ms reapplied
	6690		t = 10ms 100% V_{RRM}
	7000		t = 8.3ms reapplied
I^2t Maximum I^2t for fusing	316	KA²s	t = 10ms No voltage
	289		t = 8.3ms reapplied
	224		t = 10ms 100% V_{RRM}
	204		t = 8.3ms reapplied
$I^2\sqrt{t}$ Maximum $I^2\sqrt{t}$ for fusing	3160	KA²√s	t = 0.1 to 10ms, no voltage reapplied

On-state Conduction

Parameter	ST303C..C	Units	Conditions
V_{TM} Max. peak on-state voltage	2.16	V	$I_{TM} = 1255A$, $T_J = T_J \text{ max}$, $t_p = 10\text{ms}$ sine wave pulse
$V_{T(TO)1}$ Low level value of threshold voltage	1.44		$(16.7\% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)})$, $T_J = T_J \text{ max}$.
$V_{T(TO)2}$ High level value of threshold voltage	1.48		$(I > \pi \times I_{T(AV)})$, $T_J = T_J \text{ max}$.
r_{t1} Low level value of forward slope resistance	0.57	mΩ	$(16.7\% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)})$, $T_J = T_J \text{ max}$.
r_{t2} High level value of forward slope resistance	0.56		$(I > \pi \times I_{T(AV)})$, $T_J = T_J \text{ max}$.
I_H Maximum holding current	600	mA	$T_J = 25^\circ\text{C}$, $I_T > 30A$
I_L Typical latching current	1000		$T_J = 25^\circ\text{C}$, $V_A = 12V$, $R_a = 6\Omega$, $I_G = 1A$

Switching

Parameter	ST303C..C	Units	Conditions
di/dt Max. non-repetitive rate of rise of turned-on current	1000	A/μs	$T_J = T_J \text{ max}$, $V_{DRM} = \text{rated } V_{DRM}$ $I_{TM} = 2 \times di/dt$
t_d Typical delay time	0.83	μs	$T_J = 25^\circ\text{C}$, $V_{DM} = \text{rated } V_{DRM}$, $I_{TM} = 50A$ DC, $t_p = 1\mu\text{s}$ Resistive load, Gate pulse: 10V, 5Ω source
t_q Max. turn-off time (*)	Min 10 Max 30		$T_J = T_J \text{ max}$, $I_{TM} = 550A$, commutating $di/dt = 40A/\mu\text{s}$ $V_R = 50V$, $t_p = 500\mu\text{s}$, dv/dt : see table in device code

(*) $t_q = 10$ to $20\mu\text{s}$ for 400 to 800V devices; $t_q = 15$ to $30\mu\text{s}$ for 1000 to 1200V devices.

Blocking

Parameter	ST303C..C	Units	Conditions
dv/dt Maximum critical rate of rise of off-state voltage	500	V/μs	$T_J = T_J \text{ max}$. linear to 80% V_{DRM} , higher value available on request
I_{RRM} I_{DRM} Max. peak reverse and off-state leakage current	50	mA	$T_J = T_J \text{ max}$, rated V_{DRM}/V_{RRM} applied

Triggering

Parameter	ST303C..C	Units	Conditions
P_{GM} Maximum peak gate power	60	W	$T_J = T_J \text{ max}$, $f = 50\text{Hz}$, $d\% = 50$
$P_{G(AV)}$ Maximum average gate power	10		
I_{GM} Max. peak positive gate current	10	A	$T_J = T_J \text{ max}$, $t_p \leq 5\text{ms}$
$+V_{GM}$ Maximum peak positive gate voltage	20	V	$T_J = T_J \text{ max}$, $t_p \leq 5\text{ms}$
$-V_{GM}$ Maximum peak negative gate voltage	5		
I_{GT} Max. DC gate current required to trigger	200	mA	$T_J = 25^\circ\text{C}$, $V_A = 12V$, $R_a = 6\Omega$
V_{GT} Max. DC gate voltage required to trigger	3	V	
I_{GD} Max. DC gate current not to trigger	20	mA	$T_J = T_J \text{ max}$, rated V_{DRM} applied
V_{GD} Max. DC gate voltage not to trigger	0.25	V	

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Thermal and Mechanical Specification

Parameter	ST303C..C	Units	Conditions
T _J Max. operating temperature range	-40 to 125	°C	
T _{stg} Max. storage temperature range	-40 to 150		
R _{thJ-hs} Max. thermal resistance, junction to heatsink	0.09 0.04	K/W	DC operation single side cooled DC operation double side cooled
R _{thC-hs} Max. thermal resistance, case to heatsink	0.020 0.010	K/W	DC operation single side cooled DC operation double side cooled
F Mounting force, ± 10%	9800 (1000)	N (Kg)	
wt Approximate weight	83	g	
Case style	TO - 200AB (E-PUK)		See Outline Table

ΔR_{thJ-hs} Conduction

(The following table shows the increment of thermal resistance R_{thJ-hs} when devices operate at different conduction angles than DC)

Conduction angle	Sinusoidal conduction		Rectangular conduction		Units	Conditions
	Single Side	Double Side	Single Side	Double Side		
180°	0.010	0.010	0.007	0.007	K/W	T _J = T _J max.
120°	0.012	0.012	0.012	0.013		
90°	0.015	0.015	0.016	0.017		
60°	0.022	0.022	0.023	0.023		
30°	0.036	0.036	0.036	0.037		

Ordering Information Table

Device Code <div style="display: flex; align-items: center; justify-content: center;"> <div style="border: 1px solid black; padding: 2px 5px; margin: 2px;">ST</div> <div style="border: 1px solid black; padding: 2px 5px; margin: 2px;">30</div> <div style="border: 1px solid black; padding: 2px 5px; margin: 2px;">3</div> <div style="border: 1px solid black; padding: 2px 5px; margin: 2px;">C</div> <div style="border: 1px solid black; padding: 2px 5px; margin: 2px;">12</div> <div style="border: 1px solid black; padding: 2px 5px; margin: 2px;">C</div> <div style="border: 1px solid black; padding: 2px 5px; margin: 2px;">H</div> <div style="border: 1px solid black; padding: 2px 5px; margin: 2px;">K</div> <div style="border: 1px solid black; padding: 2px 5px; margin: 2px;">1</div> <div style="border: 1px solid black; padding: 2px 5px; margin: 2px;"></div> </div> <div style="display: flex; justify-content: center; margin-top: 5px;"> <div style="border: 1px solid black; border-radius: 50%; width: 20px; height: 20px; display: flex; align-items: center; justify-content: center; margin: 0 5px;">1</div> <div style="border: 1px solid black; border-radius: 50%; width: 20px; height: 20px; display: flex; align-items: center; justify-content: center; margin: 0 5px;">2</div> <div style="border: 1px solid black; border-radius: 50%; width: 20px; height: 20px; display: flex; align-items: center; justify-content: center; margin: 0 5px;">3</div> <div style="border: 1px solid black; border-radius: 50%; width: 20px; height: 20px; display: flex; align-items: center; justify-content: center; margin: 0 5px;">4</div> <div style="border: 1px solid black; border-radius: 50%; width: 20px; height: 20px; display: flex; align-items: center; justify-content: center; margin: 0 5px;">5</div> <div style="border: 1px solid black; border-radius: 50%; width: 20px; height: 20px; display: flex; align-items: center; justify-content: center; margin: 0 5px;">6</div> <div style="border: 1px solid black; border-radius: 50%; width: 20px; height: 20px; display: flex; align-items: center; justify-content: center; margin: 0 5px;">7</div> <div style="border: 1px solid black; border-radius: 50%; width: 20px; height: 20px; display: flex; align-items: center; justify-content: center; margin: 0 5px;">8</div> <div style="border: 1px solid black; border-radius: 50%; width: 20px; height: 20px; display: flex; align-items: center; justify-content: center; margin: 0 5px;">9</div> <div style="border: 1px solid black; border-radius: 50%; width: 20px; height: 20px; display: flex; align-items: center; justify-content: center; margin: 0 5px;">10</div> </div>									
1 - Thyristor									
2 - Essential part number									
3 - 3 = Fast turn off									
4 - C = Ceramic Puk									
5 - Voltage code: Code x 100 = V _{RRM} (See Voltage Rating Table)									
6 - C = Puk Case TO-200AB (E-PUK)									
7 - Reapplied dv/dt code (for t _q test condition)									
8 - t _q code									
9 - 0 = Eyelet term. (Gate and Aux. Cathode Unsoldered Leads)									
1 = Fast-on term. (Gate and Aux. Cathode Unsoldered Leads)									
2 = Eyelet term. (Gate and Aux. Cathode Soldered Leads)									
3 = Fast-on term. (Gate and Aux. Cathode Soldered Leads)									
10 - Critical dv/dt:									
None = 500V/μsec (Standard value)									
L = 1000V/μsec (Special selection)									

dv/dt - t _q combinations available					
dv/dt (V/μs)		20	50	100	200
t _q (μs)	10	CN	DN	EN	FN *
	12	CM	DM	EM	FM
	15	CL	DL	EL	FL *
	20	CK	DK	EK	FK *
t _q (μs)	15	CL	DP	--	--
	18	CP	--	--	--
	20	CK	DK	EK	FK *
	25	CJ	DJ	EJ	FJ *
	30	--	DH	EH	FH

*Standard part number.
All other types available only on request.

Outline Table

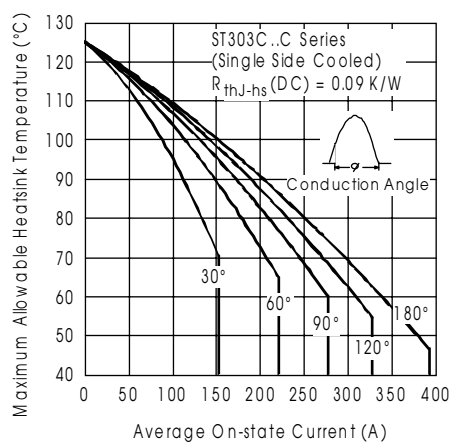
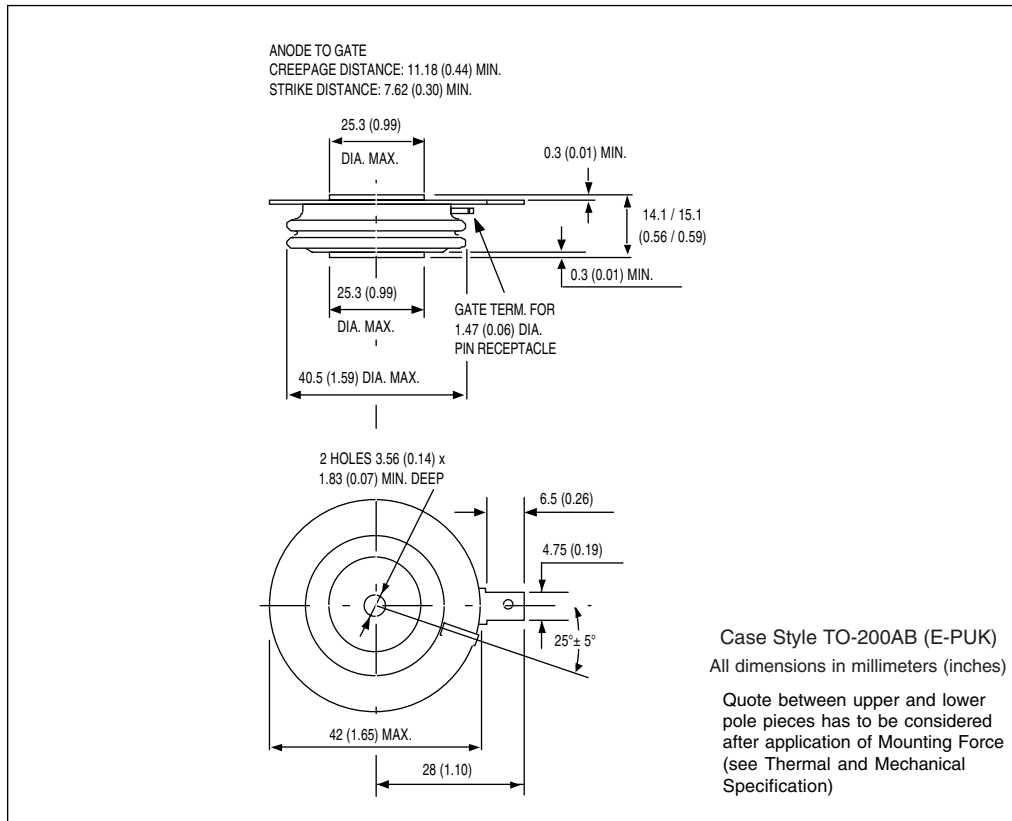


Fig. 1 - Current Ratings Characteristics

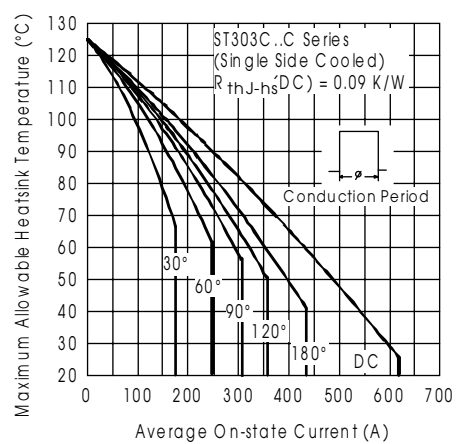


Fig. 2 - Current Ratings Characteristics

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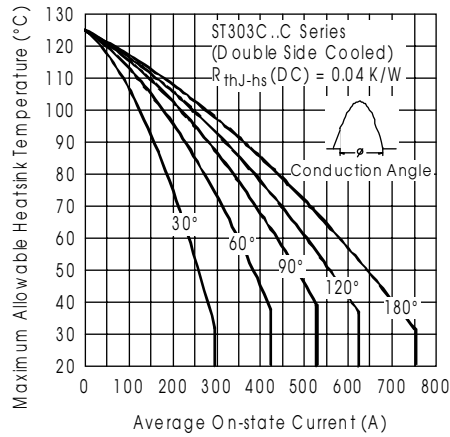


Fig. 3 - Current Ratings Characteristics

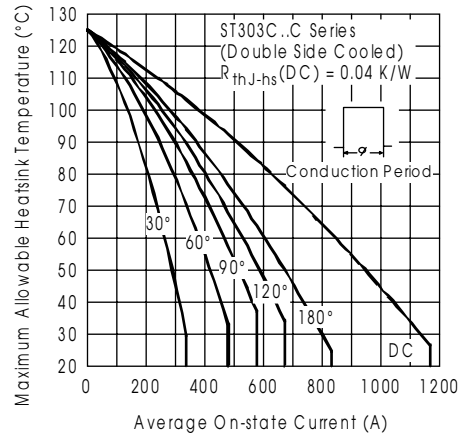


Fig. 4 - Current Ratings Characteristics

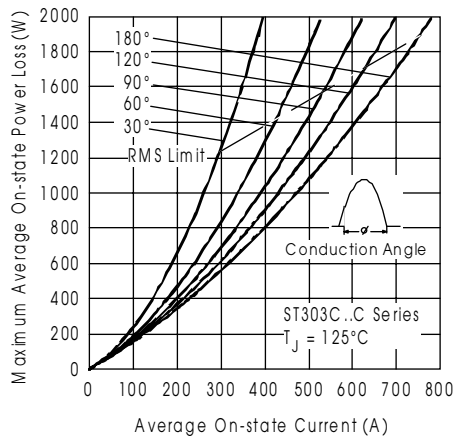


Fig. 5 - On-state Power Loss Characteristics

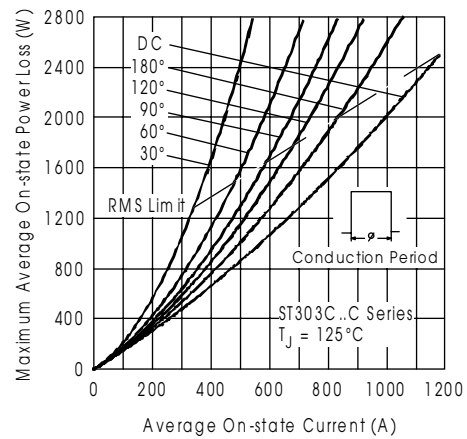


Fig. 6 - On-state Power Loss Characteristics

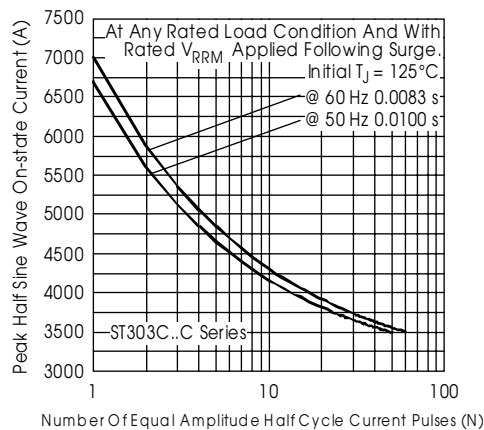


Fig. 7 - Maximum Non-repetitive Surge Current
Single and Double Side Cooled

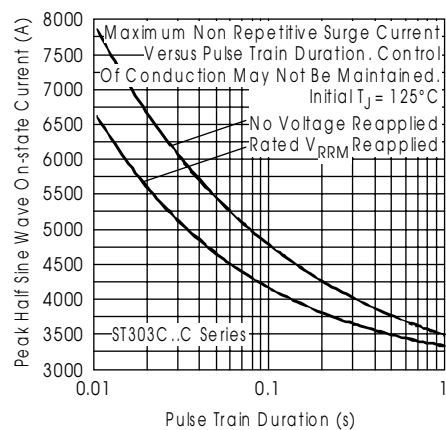


Fig. 8 - Maximum Non-repetitive Surge Current
Single and Double Side Cooled

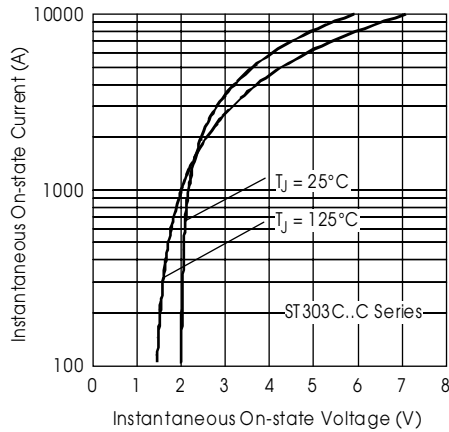


Fig. 9 - On-state Voltage Drop Characteristics

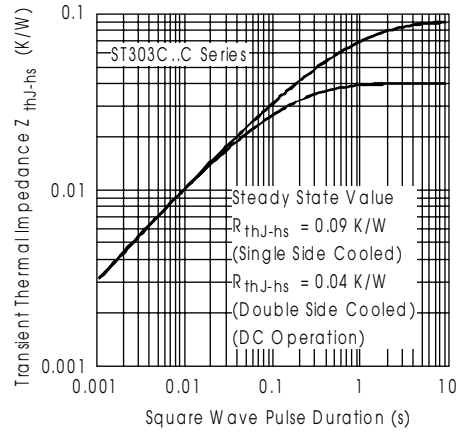


Fig. 10 - Thermal Impedance Z_{thJ-hs} Characteristics

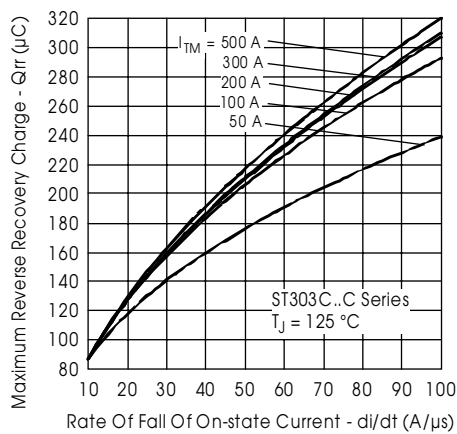


Fig. 11 - Reverse Recovered Charge Characteristics

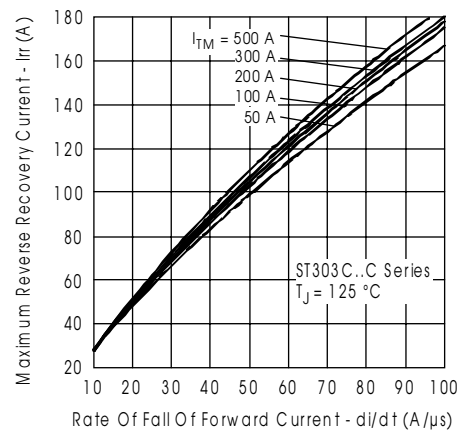


Fig. 12 - Reverse Recovery Current Characteristics

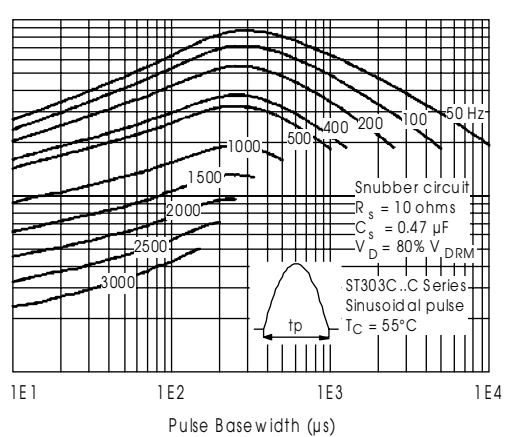
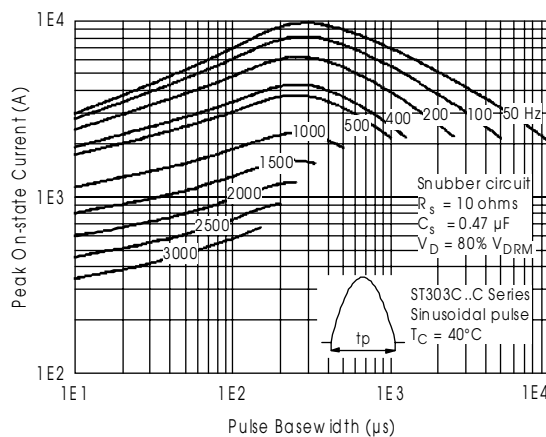


Fig. 13 - Frequency Characteristics

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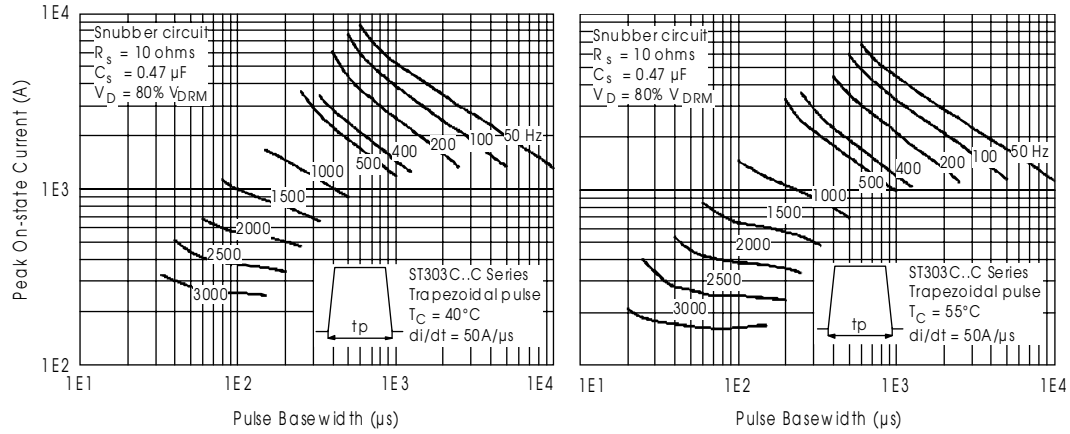


Fig. 14 - Frequency Characteristics

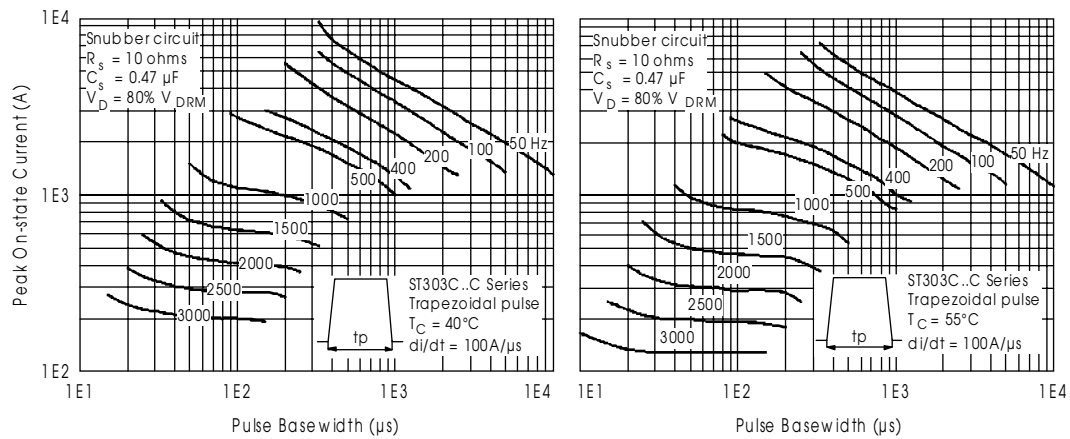


Fig. 15 - Frequency Characteristics

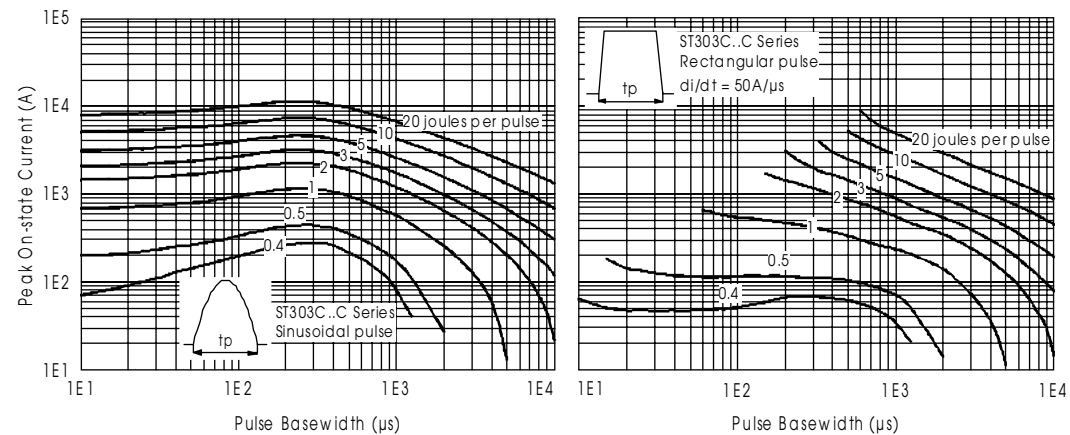


Fig. 16 - Maximum On-state Energy Power Loss Characteristics

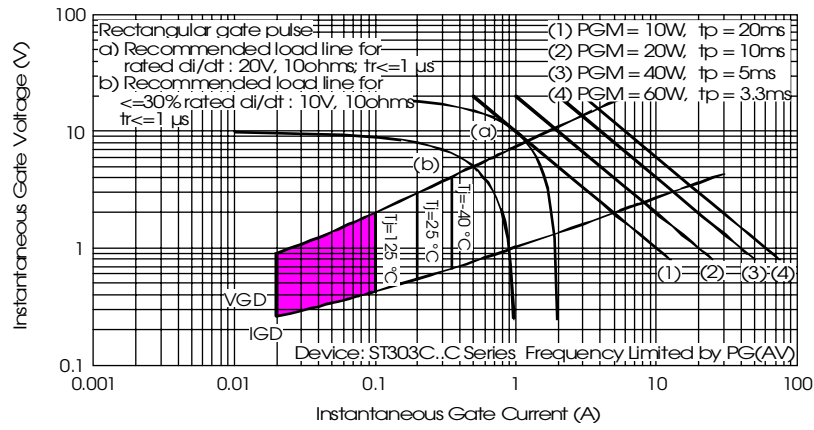


Fig. 17 - Gate Characteristics